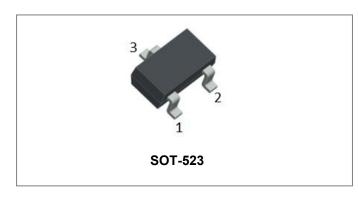




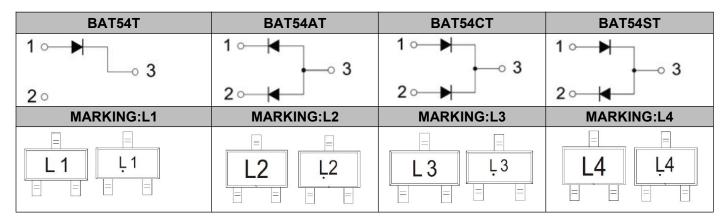


BAT54T/AT/CT/ST SCHOTTKY BARRIER DIODE



Features

- Low Forward Voltage Drop
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Solid dot = Green molding compound device, if none, the normal device.

Maximum Ratings@T_A=25°C unless otherwise specified

Symbol	Parameter	Value	Units
V_{RRM}	Peak Repetitive Reverse Voltage	20 14	
V _{RWM}	Working Peak Reverse Voltage	30	V
V _{R(RMS)}	RMS Reverse Voltage	21	V
Io	Average Rectified Output Current	0.2	Α
I _{FSM}	Non-repetitive Peak Forward Surge Current @ t=8.3ms	600	mA
I _{FRM}	Repetitive Peak Forward Surge Current @ t≤1s;δ≤0.5	300	mA
P _D	Power Dissipation	150	mW
Reja	Thermal Resistance from Junction to Ambient	667	°C/W
T _j	Junction Temperature	125	°C
T _{stg}	Storage Temperature	-55~+150	°C

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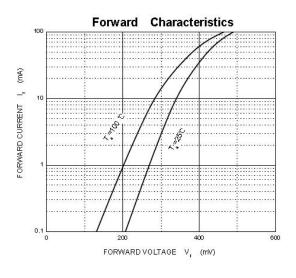


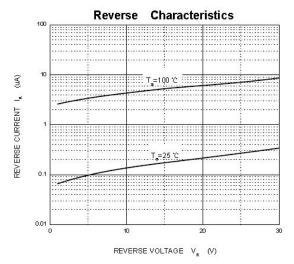
Electrical Characteristics @T_A=25°C unless otherwise specified

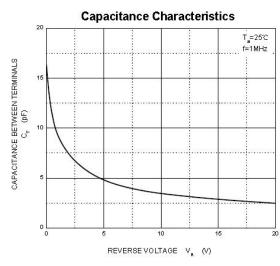
Parameter	Symbol	Test conditions	Min	Тур	Max	Units
Reverse voltage*	$V_{(BR)}$	I _R =100μA	30	-	-	V
Reverse current*	I _R	V _R =25V	-	-	2	μA
Forward voltage*	V _F	I _F =1mA	-	-	0.32	V
		I _F =10mA	-	-	0.4	1
		I _F =30mA	-	-	0.5	1
		I _F =100mA	-	-	1	1
Total capacitance	C _{tot}	V _R =1V,f=1MHz	-	-	10	pF
Reverse recovery time T _{rr}		$I_F=I_R=10$ mA, $Irr=0.1\times IR$, $R_L=100\Omega$	-	-	5	ns

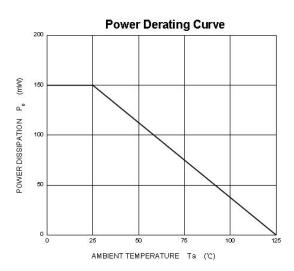
^{*} Pulse width < 300 μs, duty cycle < 2%

Ratings and Characteristics Curves









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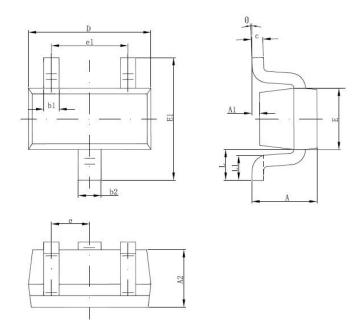


Ordering Information

Device	Package	Shipping	
BAT54T/AT/CT/ST	SOT-523(Pb-Free)	3000pcs / reel	

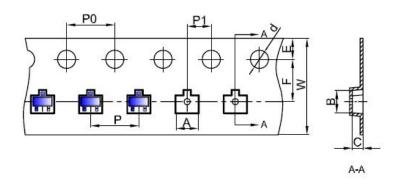
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Mechanical Dimensions SOT-523



CVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	0.700	0.900	0.028	0.035	
A1	0.000	0.100	0.000	0.004	
A2	0.700	0.800	0.028	0.031	
b1	0.150	0.250	0.006	0.010	
b2	0.250	0.350	0.010	0.014	
С	0.100	0.200	0.004	0.008	
D	1.500	1.700	0.059	0.067	
Е	0.700	0.900	0.028	0.035	
E1	1.450	1.750	0.057	0.069	
е	0.500 TYP.		0.020 TYP.		
e1	0.900	1.100	0.035	0.043	
L	0.400 REF.		0.016 REF.		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

Carrier Tape Specification SOT-523



SYMBOL	Millimeters		
STWIBUL	Min.	Max.	
Α	1.80	1.90	
В	1.80	1.90	
С	0.825	0.925	
d	1.40	1.60	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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